Si7448DP

Vishay Siliconix

N-Channel 20 V (D-S) Fast Switching MOSFET



www.vishay.com

FEATURES

- TrenchFET[®] power MOSFET
- New low thermal resistance PowerPAK[®] package with low 1.07 mm profile
- 100 % R_q tested
- Material categorization:
- for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Synchronous rectifier low output voltage
- Portable computer battery selection or protection

N-Channel MOSFET

PRODUCT SUMMARY	
V _{DS} (V)	20
$R_{DS(on)}$ max. (Ω) at V_{GS} = 4.5 V	0.0065
$R_{DS(on)}$ max. (Ω) at V_{GS} = 2.5 V	0.0090
Q _g typ. (nC)	38
I _D (A)	22
Configuration	Single

ORDERING INFORMATION	
Package	PowerPAK SO-8
Lead (Pb)-free	Si7448DP-T1-E3
Lead (Pb)-free and halogen-free	Si7448DP-T1-GE3

PARAMETER		SYMBOL	10 s	STEADY STATE	UNIT
Drain-source voltage		V _{DS}	20	20	V
Gate-source voltage		V _{GS}	± 12	± 12	
Continuous drain surrent (T 150 °C) à	T _A = 25 °C		22	13.4	
Continuous drain current (T _J = 150 °C) ^a	T _A = 70 °C	I _D	17.6	10.7	•
Pulsed drain current		I _{DM}	50	50	A
Continuous source current (diode conduction) ^a		I _S	4.3	1.6	
$T_A = 25 \text{ °C}$		P	5.2	1.9	W
Maximum power dissipation ^a	T _A = 70 °C	P _D 3.3 1.2	1.2		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +150		
Soldering recommendations (peak temperature) ^{b, c}			260		°C

THERMAL RESISTANCE RATING	GS				
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction to ambient a	t ≤ 10 s	P	19	24	
Maximum junction-to-ambient ^a	Steady state	R _{thJA}	52	65	°C/W
Maximum junction-to-case (drain)	Steady state	R _{thJC}	1.5	1.8	

Notes

a. Surface mounted on 1" x 1" FR4 board

b. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

1

c. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

S09-0270-Rev. D, 16-Feb-09

For technical questions, contact: <u>pmostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

RoHS COMPLIANT HALOGEN www.vishay.com

Vishay Siliconix

Si7448DP

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Gate threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	0.6	-	1.5	V	
Gate-body leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$	-	-	± 100	nA	
Zara gata valtaga drain ourrent		$V_{DS} = 20 V, V_{GS} = 0 V$	-	-	1		
Zero gate voltage drain current	I _{DSS}	$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 85^{\circ}\text{C}$	-	-	20	μA	
On-state drain current ^a	I _{D(on)}	$V_{DS} \geq 5~V,~V_{GS} = 4.5~V$	50	-	-	Α	
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 22 \text{ A}$	-	0.0054	0.0065		
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 19 \text{ A}$	-	0.0075	0.0090	Ω	
Forward transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 22 \text{ A}$	-	90	-	S	
Diode forward voltage ^a	V _{SD}	$I_{S} = 3 \text{ A}, V_{GS} = 0 \text{ V}$	-	0.8	1.2	V	
Dynamic ^b							
Total gate charge	Qg		-	38	50		
Gate-source charge	Q _{gs}	V_{DS} = 10 V, V_{GS} = 4.5 V, I_{D} = 21 A	-	8	-	nC	
Gate-drain charge	Q _{gd}		-	8.5	-		
Gate resistance	Rg		0.2	0.9	1.1	Ω	
Turn-on delay time	t _{d(on)}		-	22	35		
Rise time	t _r	$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = 10 \; V, \; R_{\text{L}} = 10 \; \Omega \\ I_{\text{D}} \cong 1 \; A, \; V_{\text{GEN}} = 10 \; V, \; R_{\text{g}} = 6 \; \Omega \end{array}$	-	22	35		
Turn-off delay time	t _{d(off)}		-	125	190	ns	
Fall time	t _f		-	60	90		
Source-drain reverse recovery time	t _{rr}	I _F = 3 A, di/dt = 100 A/μs	-	60	90		

Notes

a. Pulse test: pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2

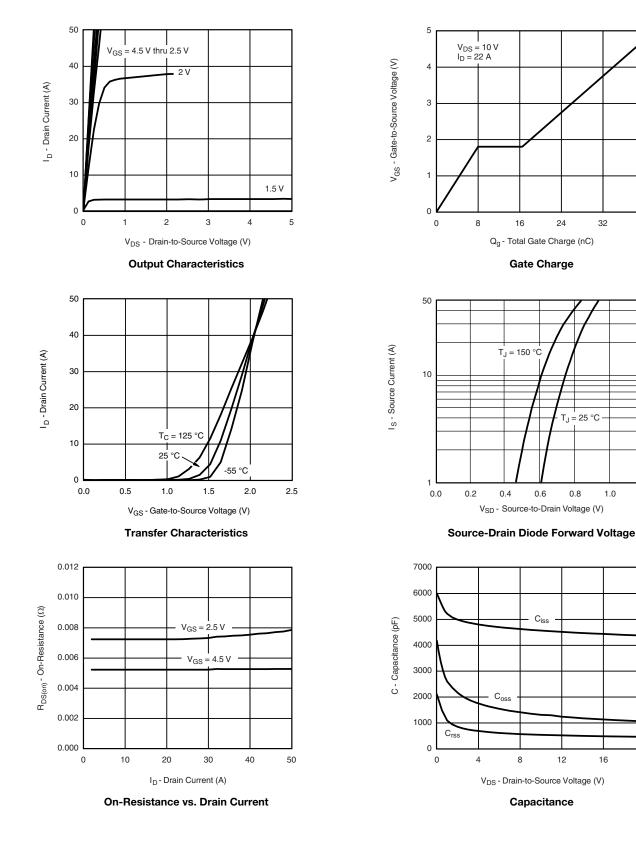


Vishay Siliconix

40

1.2

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



3

20

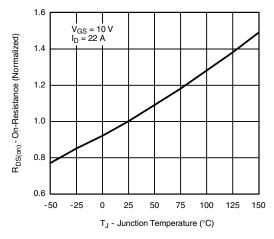
For technical questions, contact: <u>pmostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



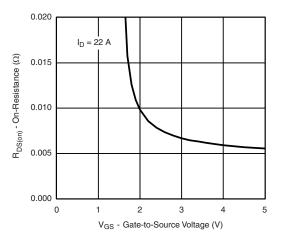


Vishay Siliconix

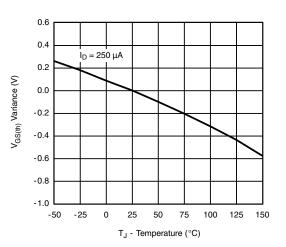
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



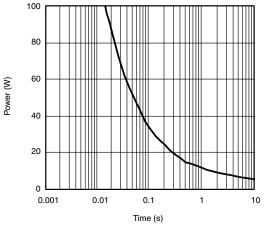
On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



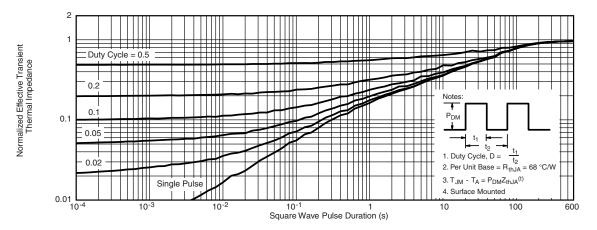
Single Pulse Power, Junction-to-Ambient

Downloaded from Arrow.com.

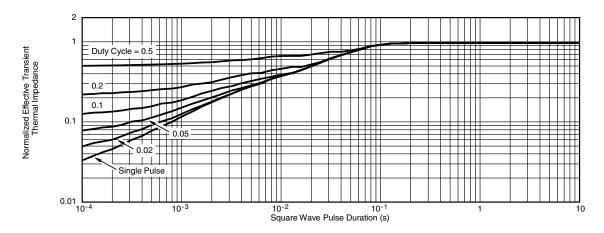


Vishay Siliconix

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71635.

S09-0270-Rev. D, 16-Feb-09	5	Document Number: 71635
For	r technical questions, contact: pmostechsupport@vishay.com	
	CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED F TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com</u>	

D2

E3

Backside View of Dual Pad



Vishay Siliconix

PowerPAK[®] SO-8, (Single/Dual)



Notes

1. Inch will govern.

2 Dimensions exclusive of mold gate burrs.

3. Dimensions exclusive of mold flash and cutting burrs.

DIM	MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX	
А	0.97	1.04	1.12	0.038	0.041	0.044	
A1		-	0.05	0	-	0.002	
b	0.33	0.41	0.51	0.013	0.016	0.020	
С	0.23	0.28	0.33	0.009	0.011	0.013	
D	5.05	5.15	5.26	0.199	0.203	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.56	3.76	3.91	0.140	0.148	0.154	
D3	1.32	1.50	1.68	0.052	0.059	0.066	
D4		0.57 typ.		0.0225 typ.			
D5		3.98 typ.			0.157 typ.		
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	5.79	5.89	5.99	0.228	0.232	0.236	
E2	3.48	3.66	3.84	0.137	0.144	0.151	
E3	3.68	3.78	3.91	0.145	0.149	0.154	
E4		0.75 typ.			0.030 typ.		
е		1.27 BSC 0.050 BSC					
К		1.27 typ.		0.050 typ.			
K1	0.56	-	-	0.022	-	-	
Н	0.51	0.61	0.71	0.020	0.024	0.028	
L	0.51	0.61	0.71	0.020	0.024	0.028	
L1	0.06	0.13	0.20	0.002	0.005	0.008	
θ	0°	-	12°	0°	-	12°	
W	0.15	0.25	0.36	0.006	0.010	0.014	
М		0.125 typ.		0.005 typ.			

Revison: 13-Feb-17

1

Document Number: 71655

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Application Note 826

Vishay Siliconix

RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.